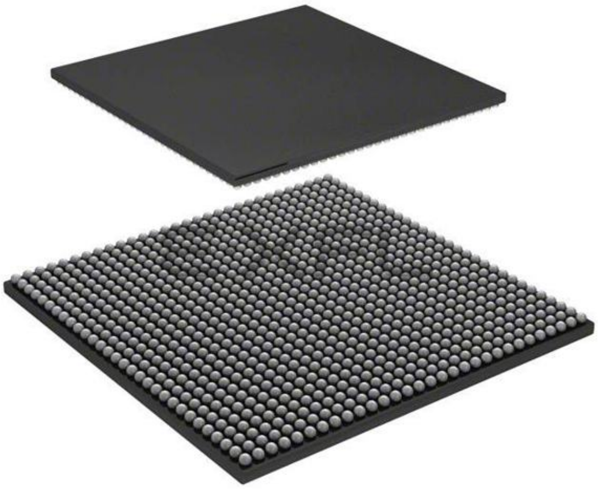
AMD Xilinx - XC6SLX150-2FG900I Datasheet



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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Active
Number of LABs/CLBs	11519
Number of Logic Elements/Cells	147443
Total RAM Bits	4939776
Number of I/O	576
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	900-BBGA
Supplier Device Package	900-FBGA (31x31)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc6slx150-2fg900i

Table 5: **Typical Quiescent Supply Current *(Cont'd)***

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
I_{CCAUXQ}	Quiescent V_{CCAUX} supply current	LX4	2.5	2.5	2.5	2.5	mA
		LX9	2.5	2.5	2.5	2.5	mA
		LX16	3.0	3.0	3.0	3.0	mA
		LX25	4.0	4.0	4.0	4.0	mA
		LX25T	4.0	4.0	4.0	N/A	mA
		LX45	5.0	5.0	5.0	5.0	mA
		LX45T	5.0	5.0	5.0	N/A	mA
		LX75	7.0	7.0	7.0	7.0	mA
		LX75T	7.0	7.0	7.0	N/A	mA
		LX100	9.0	9.0	9.0	9.0	mA
		LX100T	9.0	9.0	9.0	N/A	mA
		LX150	12.0	12.0	12.0	12.0	mA
		LX150T	12.0	12.0	12.0	N/A	mA

Notes:

1. Typical values are specified at nominal voltage, 25°C junction temperatures (Tj). Industrial (I) grade devices have the same typical values as commercial (C) grade devices at 25°C, but higher values at 100°C. Use the XPE tool to calculate 100°C values. Nominal V_{CCINT} is 1.20V; use the XPE tool to calculate 1.23V values for the nominal V_{CCINT} of the extended performance range.
2. Typical values are for blank configured devices with no output current loads, no active input pull-up resistors, all I/O pins are 3-state and floating.
3. If differential signaling is used, more accurate quiescent current estimates can be obtained by using the XPOWER Estimator (XPE) or XPOWER Analyzer (XPA) tools.

Table 6: **Power Supply Ramp Time**

Symbol	Description	Speed Grade	Ramp Time	Units
V_{CCINTR}	Internal supply voltage ramp time	-3, -3N, -2	0.20 to 50.0	ms
		-1L	0.20 to 40.0	ms
V_{CCO2}(1)	Output drivers bank 2 supply voltage ramp time	All	0.20 to 50.0	ms
V_{CCAUXR}	Auxiliary supply voltage ramp time	All	0.20 to 50.0	ms

Notes:

1. The minimum V_{CCO2} for power-on reset and configuration is 1.65V.
2. Spartan-6 FPGAs require a certain amount of supply current during power-on to insure proper device initialization. The actual current consumed depends on the power-on ramp rate of the power supply. Use the XPOWER Estimator (XPE) or XPOWER Analyzer (XPA) tools to estimate current drain on these supplies. Spartan-6 devices do not have a required power-on sequence.

eFUSE Read Endurance

Table 11 lists the minimum guaranteed number of read cycle operations for Device DNA and for the AES eFUSE key. For more information, see UG380: *Spartan-6 FPGA Configuration User Guide*.

Table 11: **eFUSE Read Endurance**

Symbol	Description	Speed Grade				Units (Min)
		-3	-3N	-2	-1L	
DNA_CYCLES	Number of DNA_PORT READ operations or JTAG ISC_DNA read command operations. Unaffected by SHIFT operations.	30,000,000				Read Cycles
AES_CYCLES	Number of JTAG FUSE_KEY or FUSE_CNTL read command operations. Unaffected by SHIFT operations.	30,000,000				Read Cycles

GTP Transceiver Specifications

GTP transceivers are available in the Spartan-6 LXT devices. See DS160: *Spartan-6 Family Overview* for more information.

GTP Transceiver DC Characteristics

Table 12: **Absolute Maximum Ratings for GTP Transceivers(1)**

Symbol	Description	MIn	Max	Units
MGTAVCC	Analog supply voltage for the GTP transmitter and receiver circuits relative to GND	–0.5	1.32	V
MGTAVTTTX	Analog supply voltage for the GTP transmitter termination circuit relative to GND	–0.5	1.32	V
MGTAVTTRX	Analog supply voltage for the GTP receiver termination circuit relative to GND	–0.5	1.32	V
MGTAVCCPLL	Analog supply voltage for the GTP transmitter and receiver PLL circuits relative to GND	–0.5	1.32	V
MGTAVTTRCAL	Analog supply voltage for the resistor calibration circuit of the GTP transceiver bank (top or bottom)	–0.5	1.32	V
V_{IN}	Receiver (RXP/RXN) and Transmitter (TXP/TXN) absolute input voltage	–0.5	1.32	V
$V_{MGTREFCLK}$	Reference clock absolute input voltage	–0.5	1.32	V

Notes:

1. Stresses beyond those listed under Absolute Maximum Ratings might cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those listed under Operating Conditions is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods of time might affect device reliability.

Table 13: **Recommended Operating Conditions for GTP Transceivers(1)(2)(3)**

Symbol	Description	Min	Typ	Max	Units
MGTAVCC	Analog supply voltage for the GTP transmitter and receiver circuits relative to GND	1.14	1.20	1.26	V
MGTAVTTTX	Analog supply voltage for the GTP transmitter termination circuit relative to GND	1.14	1.20	1.26	V
MGTAVTTRX	Analog supply voltage for the GTP receiver termination circuit relative to GND	1.14	1.20	1.26	V
MGTAVCCPLL	Analog supply voltage for the GTP transmitter and receiver PLL circuits relative to GND	1.14	1.20	1.26	V
MGTAVTTRCAL	Analog supply voltage for the resistor calibration circuit of the GTP transceiver bank (top or bottom)	1.14	1.20	1.26	V

Notes:

1. Each voltage listed requires the filter circuit described in UG386: *Spartan-6 FPGA GTP Transceivers User Guide*.
2. Voltages are specified for the temperature range of T_j = –40°C to +125°C.
3. The voltage level of MGTAVCCPLL must not exceed the voltage level of MGTAVCC +10mV. The voltage level of MGTAVCC must not exceed the voltage level of MGTAVCCPLL.

Table 23: **GTP Transceiver Receiver Switching Characteristics**

Symbol	Description			Min	Typ	Max	Units
$T_{RXELECIDLE}$	Time for RXELECIDLE to respond to loss or restoration of data			–	75	–	ns
$R_{XOOBVDPP}$	OOB detect threshold peak-to-peak			60	–	150	mV
R_{XSST}	Receiver spread-spectrum tracking(1)		Modulated @ 33 KHz	–5000	–	0	ppm
R_{XRL}	Run length (CID)	Internal AC capacitor bypassed		–	–	150	UI
$R_{XPPMTOL}$	Data/REFCLK PPM offset tolerance	CDR 2nd-order loop disabled		–200	–	200	ppm
		CDR 2nd-order loop enabled	PLL_RXDIVSEL_OUT = 1	–2000	–	2000	ppm
			PLL_RXDIVSEL_OUT = 2	–2000	–	2000	ppm
			PLL_RXDIVSEL_OUT = 4	–1000	–	1000	ppm
SJ Jitter Tolerance(2)							
$JT\_SJ_{3.125}$	Sinusoidal Jitter(3)		3.125 Gb/s	0.4	–	–	UI
$JT\_SJ_{2.5}$	Sinusoidal Jitter(3)		2.5 Gb/s	0.4	–	–	UI
$JT\_SJ_{1.62}$	Sinusoidal Jitter(3)		1.62 Gb/s	0.5	–	–	UI
$JT\_SJ_{1.25}$	Sinusoidal Jitter(3)		1.25 Gb/s	0.5	–	–	UI
JT_SJ_{614}	Sinusoidal Jitter(3)		614 Mb/s	0.5	–	–	UI
SJ Jitter Tolerance with Stressed Eye(2)(5)							
$JT\_TJSE_{3.125}$	Total Jitter with stressed eye(4)		3.125 Gb/s	0.65	–	–	UI
$JT\_SJSE_{3.125}$	Sinusoidal Jitter with stressed eye		3.125 Gb/s	0.1	–	–	UI
$JT\_TJSE_{2.7}$	Total Jitter with stressed eye(4)		2.7 Gb/s	0.65	–	–	UI
$JT\_SJSE_{2.7}$	Sinusoidal Jitter with stressed eye		2.7 Gb/s	0.1	–	–	UI

Notes:

1. Using PLL_RXDIVSEL_OUT = 1, 2, and 4.
2. All jitter values are based on a Bit Error Ratio of $1e^{-12}$.
3. Using 80 MHz sinusoidal jitter only in the absence of deterministic and random jitter.
4. Composed of 0.37 UI DJ in the form of ISI and 0.18 UI RJ.
5. Measured using PRBS7 data pattern.

Endpoint Block for PCI Express Designs Switching Characteristics

The Endpoint block for PCI Express is available in the Spartan-6 LXT devices. Consult the Spartan-6 FPGA Integrated Endpoint Block for PCI Express for further information.

Table 24: **Maximum Performance for PCI Express Designs**

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
$F_{PCIEUSER}$	User clock maximum frequency	62.5	62.5	62.5	N/A	MHz

Switching Characteristics

All values represented in this data sheet are based on these speed specifications: v1.20 for -3, -3N, and -2; and v1.08 for -1L. Switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

Advance

These specifications are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

Preliminary

These specifications are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

Production

These specifications are released once enough production silicon of a particular device family member has been characterized to provide full correlation between specifications and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to Production before faster speed grades.

All specifications are always representative of worst-case supply voltage and junction temperature conditions.

Since individual family members are produced at different times, the migration from one category to another depends completely on the status of the fabrication process for each device.

The -1L speed grade refers to the lower-power Spartan-6 devices. The -3N speed grade refers to the Spartan-6 devices that do not support MCB functionality.

Table 26 correlates the current status of each Spartan-6 device on a per speed grade basis.

Table 26: **Spartan-6 Device Speed Grade Designations**

Device	Speed Grade Designations		
	Advance	Preliminary	Production
XC6SLX4(1)			-3, -2, -1L
XC6SLX9			-3, -3N, -2, -1L
XC6SLX16			-3, -3N, -2, -1L
XC6SLX25			-3, -3N, -2, -1L
XC6SLX25T			-3, -3N, -2
XC6SLX45			-3, -3N, -2, -1L
XC6SLX45T			-3, -3N, -2
XC6SLX75			-3, -3N, -2, -1L
XC6SLX75T			-3, -3N, -2
XC6SLX100			-3, -3N, -2, -1L
XC6SLX100T			-3, -3N, -2
XC6SLX150			-3, -3N, -2, -1L
XC6SLX150T			-3, -3N, -2
XA6SLX4			-3, -2
XA6SLX9			-3, -2
XA6SLX16			-3, -2
XA6SLX25			-3, -2
XA6SLX25T			-3, -2
XA6SLX45			-3, -2
XA6SLX45T			-3, -2
XA6SLX75			-3, -2
XA6SLX75T			-3, -2
XA6SLX100			-2
XQ6SLX75			-2, -1L
XQ6SLX75T			-3, -2
XQ6SLX150			-2, -1L
XQ6SLX150T			-3, -2

Notes:

1. The XC6SLX4 is not available in the -3N speed grade.

Testing of Switching Characteristics

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values.

For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer and back-annotate to the simulation net list. Unless otherwise noted, values apply to all Spartan-6 devices.

Table 29: **IOB Switching Characteristics for the Automotive XA Spartan-6 and the Spartan-6Q Devices**[1] ***(Cont'd)***

I/O Standard	T_{IOPI}		T_{IOOP}		T_{IOTP}		Units
	Speed Grade		Speed Grade		Speed Grade		
	-3	-2	-3	-2	-3	-2	
LVCMOS15, QUIETIO, 2 mA	1.05	1.23	5.63	5.83	5.63	5.83	ns
LVCMOS15, QUIETIO, 4 mA	1.05	1.23	4.75	4.95	4.75	4.95	ns
LVCMOS15, QUIETIO, 6 mA	1.05	1.23	4.21	4.41	4.21	4.41	ns
LVCMOS15, QUIETIO, 8 mA	1.05	1.23	4.05	4.25	4.05	4.25	ns
LVCMOS15, QUIETIO, 12 mA	1.05	1.23	3.74	3.94	3.74	3.94	ns
LVCMOS15, QUIETIO, 16 mA	1.05	1.23	3.52	3.72	3.52	3.72	ns
LVCMOS15, Slow, 2 mA	1.05	1.23	4.32	4.52	4.32	4.52	ns
LVCMOS15, Slow, 4 mA	1.05	1.23	3.58	3.78	3.58	3.78	ns
LVCMOS15, Slow, 6 mA	1.05	1.23	2.45	2.65	2.45	2.65	ns
LVCMOS15, Slow, 8 mA	1.05	1.23	2.46	2.66	2.46	2.66	ns
LVCMOS15, Slow, 12 mA	1.05	1.23	2.17	2.37	2.17	2.37	ns
LVCMOS15, Slow, 16 mA	1.05	1.23	2.15	2.35	2.15	2.35	ns
LVCMOS15, Fast, 2 mA	1.05	1.23	3.43	3.63	3.43	3.63	ns
LVCMOS15, Fast, 4 mA	1.05	1.23	2.42	2.62	2.42	2.62	ns
LVCMOS15, Fast, 6 mA	1.05	1.23	1.92	2.12	1.92	2.12	ns
LVCMOS15, Fast, 8 mA	1.05	1.23	1.87	2.07	1.87	2.07	ns
LVCMOS15, Fast, 12 mA	1.05	1.23	1.87	2.07	1.87	2.07	ns
LVCMOS15, Fast, 16 mA	1.05	1.23	1.87	2.07	1.87	2.07	ns
LVCMOS15_JEDEC, QUIETIO, 2 mA	1.10	1.28	5.64	5.84	5.64	5.84	ns
LVCMOS15_JEDEC, QUIETIO, 4 mA	1.10	1.28	4.75	4.95	4.75	4.95	ns
LVCMOS15_JEDEC, QUIETIO, 6 mA	1.10	1.28	4.21	4.41	4.21	4.41	ns
LVCMOS15_JEDEC, QUIETIO, 8 mA	1.10	1.28	4.06	4.26	4.06	4.26	ns
LVCMOS15_JEDEC, QUIETIO, 12 mA	1.10	1.28	3.75	3.95	3.75	3.95	ns
LVCMOS15_JEDEC, QUIETIO, 16 mA	1.10	1.28	3.53	3.73	3.53	3.73	ns
LVCMOS15_JEDEC, Slow, 2 mA	1.10	1.28	4.32	4.52	4.32	4.52	ns
LVCMOS15_JEDEC, Slow, 4 mA	1.10	1.28	3.56	3.76	3.56	3.76	ns
LVCMOS15_JEDEC, Slow, 6 mA	1.10	1.28	2.44	2.64	2.44	2.64	ns
LVCMOS15_JEDEC, Slow, 8 mA	1.10	1.28	2.47	2.67	2.47	2.67	ns
LVCMOS15_JEDEC, Slow, 12 mA	1.10	1.28	2.15	2.35	2.15	2.35	ns
LVCMOS15_JEDEC, Slow, 16 mA	1.10	1.28	2.15	2.35	2.15	2.35	ns
LVCMOS15_JEDEC, Fast, 2 mA	1.10	1.28	3.43	3.63	3.43	3.63	ns
LVCMOS15_JEDEC, Fast, 4 mA	1.10	1.28	2.42	2.62	2.42	2.62	ns
LVCMOS15_JEDEC, Fast, 6 mA	1.10	1.28	1.92	2.12	1.92	2.12	ns
LVCMOS15_JEDEC, Fast, 8 mA	1.10	1.28	1.87	2.07	1.87	2.07	ns
LVCMOS15_JEDEC, Fast, 12 mA	1.10	1.28	1.87	2.07	1.87	2.07	ns
LVCMOS15_JEDEC, Fast, 16 mA	1.10	1.28	1.87	2.07	1.87	2.07	ns
LVCMOS12, QUIETIO, 2 mA	0.98	1.16	6.54	6.74	6.54	6.74	ns
LVCMOS12, QUIETIO, 4 mA	0.98	1.16	5.12	5.32	5.12	5.32	ns

Table 34: **SSO Limit per V_{CCO}/GND Pair *(Cont'd)***

V_{CCO}	I/O Standard	Drive	Slew	SSO Limit per V_{CCO}/GND Pair			
				All TQG144, CPG196, CSG225, FT(G)256, and LX devices in CSG324		All CS(G)484, FG(G)484, FG(G)676, FG(G)900, and LXT devices in CSG324	
				Bank 0/2	Bank 1/3	Bank 0/2	Bank 1/3/4/5
3.3V	LVTTL	2	Fast	53	65	53	62
			Slow	70	80	70	73
			QuietIO	79	89	79	91
		4	Fast	23	30	23	27
			Slow	34	41	34	37
			QuietIO	44	49	44	46
		6	Fast	16	21	16	20
			Slow	21	28	21	25
			QuietIO	34	39	34	34
		8	Fast	12	16	12	15
			Slow	16	22	16	19
			QuietIO	27	28	27	24
		12	Fast	1	3	1	1
			Slow	2	5	2	4
			QuietIO	2	10	2	8
		16	Fast	1	3	1	1
			Slow	1	7	1	2
			QuietIO	3	11	3	8
		24	Fast	1	2	1	1
			Slow	2	5	2	2
			QuietIO	8	9	8	8
	PCI33_3			18	19	18	19
	PCI66_3			18	19	18	19
	SSTL_3_I			5	8	5	8
	SSTL_3_II			3	5	3	3
	DIFF_SSTL_3_I			15	24	15	24
	DIFF_SSTL_3_II			9	15	9	9
	SDIO			17	18	17	15

Input/Output Logic Switching Characteristics

Table 35: **ILOGIC2 Switching Characteristics**

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
Setup/Hold						
T_{ICE0CK}/T_{ICKCE0}	CE0 pin Setup/Hold with respect to CLK	0.56/–0.30	0.56/–0.25	0.79/–0.22	1.21/–0.52	ns
T_{ISRCK}/T_{ICKSR}	SR pin Setup/Hold with respect to CLK	0.74/–0.23	0.74/–0.22	0.98/–0.20	1.31/–0.45	ns
T_{IDOCK}/T_{IOCKD}	D pin Setup/Hold with respect to CLK without Delay	1.19/–0.83	1.36/–0.83	1.73/–0.83	2.18/–1.77	ns
T_{IDOCKD}/T_{IOCKDD}	DDLY pin Setup/Hold with respect to CLK (using IODELAY2)	0.31/0.00	0.47/0.00	0.54/0.00	0.63/–0.39	ns
Combinatorial						
T_{IDI}	D pin to O pin propagation delay, no Delay	0.95	1.28	1.53	2.25	ns
T_{IDID}	DDLY pin to O pin propagation delay (using IODELAY2)	0.23	0.39	0.44	0.74	ns
Sequential Delays						
T_{IDLO}	D pin to Q pin using flip-flop as a latch without Delay	1.56	1.86	2.39	3.49	ns
T_{IDLOD}	DDLY pin to Q1 pin using flip-flop as a latch (using IODELAY2)	0.68	0.97	1.20	1.94	ns
T_{ICKQ}	CLK to Q outputs for XC devices	1.03	1.24	1.43	2.11	ns
	CLK to Q outputs for XA and XQ devices	1.38	N/A	1.78	2.11	ns
$T_{RQ\_ILOGIC2}$	SR pin to Q outputs	1.81	1.81	2.50	3.05	ns

Table 36: **OLOGIC2 Switching Characteristics**

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
Setup/Hold						
T_{ODCK}/T_{OCKD}	D1/D2 pins Setup/Hold with respect to CLK	0.81/–0.05	0.86/–0.05	1.18/0.00	1.73/–0.27	ns
T_{OOCECK}/T_{OCKOCE}	OCE pin Setup/Hold with respect to CLK	0.75/–0.10	0.75/–0.10	1.01/–0.05	1.66/–0.23	ns
T_{OSRCK}/T_{OCKSR}	SR pin Setup/Hold with respect to CLK	0.70/–0.28	0.79/–0.28	1.03/–0.23	1.39/–0.47	ns
T_{OTCK}/T_{OCKT}	T1/T2 pins Setup/Hold with respect to CLK	0.24/–0.08	0.56/–0.06	0.83/–0.01	0.99/–0.19	ns
T_{OTCECK}/T_{OCKTCE}	TCE pin Setup/Hold with respect to CLK	0.58/–0.06	0.72/–0.06	1.18/–0.01	1.51/–0.13	ns
Sequential Delays						
T_{OCKQ}	CLK to OQ/TQ out for XC devices	0.48	0.51	0.74	0.74	ns
	CLK to OQ/TQ out for XA and XQ devices	0.85	N/A	1.16	0.74	ns
$T_{RQ\_OLOGIC2}$	SR pin to OQ/TQ out	1.81	1.81	2.50	3.05	ns

Block RAM Switching Characteristics

Table 43: **Block RAM Switching Characteristics**

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
Block RAM Clock to Out Delays						
T_{RCKO_DO}	Clock CLK to DOUT output (without output register)(1)	1.85	2.10	2.10	3.50	ns, Max
$T_{RCKO\_DO\_REG}$	Clock CLK to DOUT output (with output register)(2)	1.60	1.75	1.75	2.30	ns, Max
Setup and Hold Times Before/After Clock CLK						
$T_{RCCK\_ADDR}/T_{RCKC\_ADDR}$	ADDR inputs for XC devices(3)	0.35/0.10	0.40/0.12	0.40/0.12	0.50/0.15	ns, Min
	ADDR inputs for XA and XQ devices(3)	0.35/0.17	N/A	0.40/0.17	0.50/0.15	ns, Min
T_{RDCK_DI}/T_{RCKD_DI}	DIN inputs(4)	0.30/0.10	0.30/0.10	0.30/0.10	0.40/0.15	ns, Min
T_{RCCK_EN}/T_{RCKC_EN}	Block RAM Enable (EN) input	0.22/0.05	0.25/0.06	0.25/0.06	0.44/0.10	ns, Min
$T_{RCCK\_REGCE}/T_{RCKC\_REGCE}$	CE input of output register	0.20/0.10	0.20/0.10	0.20/0.10	0.28/0.15	ns, Min
T_{RCCK_WE}/T_{RCKC_WE}	Write Enable (WE) input	0.25/0.10	0.33/0.10	0.33/0.10	0.28/0.15	ns, Min
Maximum Frequency						
F_{MAX}	Block RAM in all modes	320	280	280	150	MHz

Notes:

1. T_{RCKO_DO} includes T_{RCKO_DOA} and T_{RCKO_DOPA} as well as the B port equivalent timing parameters.
2. $T_{RCKO\_DO\_REG}$ includes $T_{RCKO\_DOA\_REG}$ and $T_{RCKO\_DOPA\_REG}$ as well as the B port equivalent timing parameters.
3. The ADDR setup and hold must be met when EN is asserted (even when WE is deasserted). Otherwise, block RAM data corruption is possible.
4. T_{RDCK_DI} includes both A and B inputs as well as the parity inputs of A and B.

Table 47: **Configuration Switching Characteristics(1)** ***(Cont'd)***

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
BPI Master Flash Mode Programming Switching(4)						
T_{BPICCO}(5)	A[25:0], FCS_B, FOE_B, FWE_B, LDC outputs valid after CCLK falling edge	15	15	15	20	ns, Max
$T_{BPIICCK}$	Master BPI CCLK (output) delay	10/100	10/100	10/100	10/130	µs, Min/Max
T_{BPIDCC}/T_{BPICCD}	Setup/Hold on D[15:0] data input pins	5.0/1.0	5.0/1.0	5.0/1.0	6.0/2.0	ns, Min
SPI Master Flash Mode Programming Switching(6)						
$T_{SPIDCC}/T_{SPIDCCD}$	DIN, MISO0, MISO1, MISO2, MISO3, Setup/Hold before/after the rising CCLK edge	5.0/1.0	5.0/1.0	5.0/1.0	7.0/1.0	ns, Min
$T_{SPIICCK}$	Master SPI CCLK (output) delay	0.4/7.0	0.4/7.0	0.4/7.0	0.4/10.0	µs, Min/Max
T_{SPICCM}	MOSI clock to out	13	13	13	19	ns, Max
$T_{SPICCFC}$	CSO_B clock to out	16	16	16	26	ns, Max
CCLK Output (Master Modes)						
T_{MCCKL}	Master CCLK clock duty cycle Low	40/60				%, Min/Max
T_{MCCKH}	Master CCLK clock duty cycle High	40/60				%, Min/Max
F_{MCCK}	Maximum frequency, serial mode (Master Serial/SPI) All devices	40	40	40	30	MHz, Max
	Maximum frequency, parallel mode (Master SelectMAP/BPI) LX9, LX16, LX25, LX25T, LX45, LX45T, LX75, and LX75T	40	40	40	25	MHz, Max
	Maximum frequency, parallel mode (Master SelectMAP/BPI) LX100 and LX100T in x8 mode, LX150, and LX150T	40	40	40	20	MHz, Max
	Maximum frequency, parallel mode (Master SelectMAP/BPI) LX100 and LX100T in x16 mode	35	35	35	20	MHz, Max
$F_{MCCKTOL}$	Frequency Tolerance, master mode	±50	±50	±50	±50	%
CCLK Input (Slave Modes)						
T_{SCCKL}	Slave CCLK clock minimum Low time	5	5	5	8	ns, Min
T_{SCCKH}	Slave CCLK clock minimum High time	5	5	5	8	ns, Min
USERCCLK Input						
$T_{USERCCLKL}$	USERCCLK clock minimum Low time	12	12	12	16	ns, Min
$T_{USERCCLKH}$	USERCCLK clock minimum High time	12	12	12	16	ns, Min
$F_{USERCCLK}$	Maximum USERCCLK frequency	40	40	40	30	MHz, Max

Notes:

1. Maximum frequency and setup/hold timing parameters are for 3.3V and 2.5V configuration voltages.
2. To support longer delays in configuration, use the design solutions described in UG380: *Spartan-6 FPGA Configuration User Guide*.
3. Table 6 specifies the power supply ramp time.
4. BPI mode is not supported in:
   - LX4, LX25, or LX25T devices
   - LX9 devices in the TQG144 package
   - LX9 or LX16 devices in the CPG196 package.
5. Only during configuration, the last edge is determined by a weak pull-up/pull-down resistor in the I/O.
6. Defense-grade Spartan-6Q -2Q devices configure in single default SPI Master (x1) mode at T_j = –55°C. During operation and when using all other configuration functions, the minimum operating temperature is –40°C.

DCM Switching Characteristics

Table 53: **Operating Frequency Ranges and Conditions for the Delay-Locked Loop (DLL)(1)**

Symbol	Description	Speed Grade								Units
		-3		-3N		-2		-1L		
		Min	Max	Min	Max	Min	Max	Min	Max	
Input Frequency Ranges										
CLKIN_FREQ_DLL	Frequency of the CLKIN clock input when the CLKDV output is not used.	5(2)	280(3)	5(2)	280(3)	5(2)	250(3)	5(2)	175(3)	MHz
	Frequency of the CLKIN clock input when using the CLKDV output.	5(2)	280(3)	5(2)	280(3)	5(2)	250(3)	5(2)	133(3)	MHz
Input Pulse Requirements										
CLKIN_PULSE	CLKIN pulse width as a percentage of the CLKIN period for CLKIN_FREQ_DLL < 150 MHz	40	60	40	60	40	60	40	60	%
	CLKIN pulse width as a percentage of the CLKIN period for CLKIN_FREQ_DLL > 150 MHz	45	55	45	55	45	55	45	55	%
Input Clock Jitter Tolerance and Delay Path Variation(4)										
CLKIN_CYC_JITT_DLL_LF	Cycle-to-cycle jitter at the CLKIN input for CLKIN_FREQ_DLL < 150 MHz	–	±300	–	±300	–	±300	–	±300	ps
CLKIN_CYC_JITT_DLL_HF	Cycle-to-cycle jitter at the CLKIN input for CLKIN_FREQ_DLL > 150 MHz.	–	±150	–	±150	–	±150	–	±150	ps
CLKIN_PER_JITT_DLL	Period jitter at the CLKIN input.	–	±1	–	±1	–	±1	–	±1	ns
CLKFB_DELAY_VAR_EXT	Allowable variation of the off-chip feedback delay from the DCM output to the CLKFB input.	–	±1	–	±1	–	±1	–	±1	ns

Notes:

1. DLL specifications apply when using any of the DLL outputs: CLK0, CLK90, CLK180, CLK270, CLK2X, CLK2X180, or CLKDV.
2. When operating independently of the DLL, the DFS supports lower CLKIN_FREQ_DLL frequencies. See Table 55.
3. The CLKIN_DIVIDE_BY_2 attribute increases the effective input frequency range. When set to TRUE, the input clock frequency is divided by two as it enters the DCM. Input clock frequencies for the clock buffer being used can be increased up to the F_{MAX} (see Table 48 and Table 49 for BUFG and BUFIO2 limits). When used with CLK_FEEDBACK=2X, the input clock frequency matches the frequency for CLK2X, and is limited to CLKOUT_FREQ_2X.
4. CLKIN_FREQ_DLL input jitter beyond these limits can cause the DCM to lose LOCK, indicated by the LOCKED output deasserting. The user must then reset the DCM.
5. When using both DCMs in a CMT, both DCMs must be LOCKED.

Table 54: **Switching Characteristics for the Delay-Locked Loop (DLL)(1)**

Symbol	Description	Speed Grade								Units
		-3		-3N		-2		-1L		
		Min	Max	Min	Max	Min	Max	Min	Max	
Output Frequency Ranges										
CLKOUT_FREQ_CLK0	Frequency for the CLK0 and CLK180 outputs.	5	280	5	280	5	250	5	175	MHz
CLKOUT_FREQ_CLK90	Frequency for the CLK90 and CLK270 outputs.	5	200	5	200	5	200	5	175	MHz
CLKOUT_FREQ_2X	Frequency for the CLK2X and CLK2X180 outputs.	10	375	10	375	10	334	10	250	MHz
CLKOUT_FREQ_DV	Frequency for the CLKDV output.	0.3125	186	0.3125	186	0.3125	166	0.3125	88.6	MHz
Output Clock Jitter(2)(3)(4)										
CLKOUT_PER_JITT_0	Period jitter at the CLK0 output.	–	±100	–	±100	–	±100	–	±100	ps
CLKOUT_PER_JITT_90	Period jitter at the CLK90 output.	–	±150	–	±150	–	±150	–	±150	ps
CLKOUT_PER_JITT_180	Period jitter at the CLK180 output.	–	±150	–	±150	–	±150	–	±150	ps
CLKOUT_PER_JITT_270	Period jitter at the CLK270 output.	–	±150	–	±150	–	±150	–	±150	ps
CLKOUT_PER_JITT_2X	Period jitter at the CLK2X and CLK2X180 outputs.	Maximum = ±[0.5% of CLKIN period + 100]								ps
CLKOUT_PER_JITT_DV1	Period jitter at the CLKDV output when performing integer division.	–	±150	–	±150	–	±150	–	±150	ps
CLKOUT_PER_JITT_DV2	Period jitter at the CLKDV output when performing non-integer division.	Maximum = ±[0.5% of CLKIN period + 100]								ps
Duty Cycle(4)										
CLKOUT_DUTY_CYCLE_DLL	Duty cycle variation for the CLK0, CLK90, CLK180, CLK270, CLK2X, CLK2X180, and CLKDV outputs, including the BUFGMUX and clock tree duty-cycle distortion.	Typical = ±[1% of CLKIN period + 350]								ps
Phase Alignment(4)										
CLKIN_CLKFB_PHASE	Phase offset between the CLKIN and CLKFB inputs (CLK_FEEDBACK = 1X).	–	±150	–	±150	–	±150	–	±250	ps
	Phase offset between the CLKIN and CLKFB inputs (CLK_FEEDBACK = 2X).(6)	–	±250	–	±250	–	±250	–	±350	
CLKOUT_PHASE_DLL	Phase offset between DLL outputs for CLK0 to CLK2X (not CLK2X180).	Maximum = ±[1% of CLKIN period + 100]								ps
	Phase offset between DLL outputs for all others.	Maximum = ±[1% of CLKIN period + 150]						Maximum = ±[1% of CLKIN period + 200]		ps

Table 59: Switching Characteristics for the Phase-Shift Clock in Variable Phase Mode(1)

Symbol	Description	Amount of Phase Shift	Units
Phase Shifting Range			
MAX_STEPS(2)	When CLKIN < 60 MHz, the maximum allowed number of DCM_DELAY_STEP steps for a given CLKIN clock period, where T = CLKIN clock period in ns. When using CLKIN_DIVIDE_BY_2 = TRUE, double the clock-effective clock period.	±(INTEGER(10 x (TCLKIN – 3 ns)))	steps
	When CLKIN ≥ 60 MHz, the maximum allowed number of DCM_DELAY_STEP steps for a given CLKIN clock period, where T = CLKIN clock period in ns. When using CLKIN_DIVIDE_BY_2 = TRUE, double the clock-effective clock period.	±(INTEGER(15 x (TCLKIN – 3 ns)))	steps
FINE_SHIFT_RANGE_MIN	Minimum guaranteed delay for variable phase shifting.	±(MAX_STEPS x DCM_DELAY_STEP_MIN)	ps
FINE_SHIFT_RANGE_MAX	Maximum guaranteed delay for variable phase shifting	±(MAX_STEPS x DCM_DELAY_STEP_MAX)	ps

Notes:

1. The values in this table are based on the operating conditions described in Table 53 and Table 58.
2. The maximum variable phase shift range, MAX_STEPS, is only valid when the DCM has no initial fixed-phase shifting, that is, the PHASE_SHIFT attribute is set to 0.
3. The DCM_DELAY_STEP values are provided at the end of Table 54.

Table 60: Miscellaneous DCM Timing Parameters(1)

Symbol	Description	Min	Max	Units
DCM_RST_PW_MIN	Minimum duration of a RST pulse width	3	–	CLKIN cycles

Notes:

1. This limit only applies to applications that use the DCM DLL outputs (CLK0, CLK90, CLK180, CLK270, CLK2X, CLK2X180, and CLKDV). The DCM DFS outputs (CLKFX, CLKFXDV, CLKFX180) are unaffected.

Table 61: Frequency Synthesis

Attribute	Min	Max
CLKFX_MULTIPLY (DCM_SP)	2	32
CLKFX_DIVIDE (DCM_SP)	1	32
CLKDV_DIVIDE (DCM_SP)	1.5	16
CLKFX_MULTIPLY (DCM_CLKGEN)	2	256
CLKFX_DIVIDE (DCM_CLKGEN)	1	256
CLKFXDV_DIVIDE (DCM_CLKGEN)	2	32

Table 62: DCM Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
T_{DMCCK_PSEN}/ T_{DMCKC_PSEN}	PSEN Setup/Hold	1.50/ 0.00	1.50/ 0.00	1.50/ 0.00	1.50/ 0.00	ns
$T_{DMCCK\_PSINCDEC}$/ $T_{DMCKC\_PSINCDEC}$	PSINCDEC Setup/Hold	1.50/ 0.00	1.50/ 0.00	1.50/ 0.00	1.50/ 0.00	ns
T_{DMCKO_PSDONE}	Clock to out of PSDONE	1.50	1.50	1.50	1.50	ns

Table 65: **Global Clock Input to Output Delay With DCM in Source-Synchronous Mode**

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
LVCMOS25 Global Clock Input to Output Delay using Output Flip-Flop, 12mA, Fast Slew Rate, *with* DCM in Source-Synchronous Mode.							
$T_{ICKOFDCM\_0}$	Global Clock and OUTFF *with* DCM	XC6SLX4	5.03	N/A	7.21	8.05	ns
		XC6SLX9	5.03	6.13	7.21	8.05	ns
		XC6SLX16	5.08	5.51	6.44	7.96	ns
		XC6SLX25	4.81	5.13	5.69	7.94	ns
		XC6SLX25T	4.81	5.13	5.69	N/A	ns
		XC6SLX45	5.26	5.69	6.63	7.92	ns
		XC6SLX45T	5.26	5.69	6.63	N/A	ns
		XC6SLX75	4.77	5.18	5.88	7.95	ns
		XC6SLX75T	4.77	5.18	5.88	N/A	ns
		XC6SLX100	4.72	5.11	5.76	8.59	ns
		XC6SLX100T	4.76	5.11	5.76	N/A	ns
		XC6SLX150	4.90	5.30	5.93	7.93	ns
		XC6SLX150T	4.90	5.30	5.93	N/A	ns
		XA6SLX4	5.35	N/A	7.21	N/A	ns
		XA6SLX9	5.35	N/A	7.21	N/A	ns
		XA6SLX16	5.42	N/A	6.44	N/A	ns
		XA6SLX25	5.13	N/A	5.69	N/A	ns
		XA6SLX25T	5.13	N/A	5.79	N/A	ns
		XA6SLX45	5.58	N/A	6.63	N/A	ns
		XA6SLX45T	5.58	N/A	6.63	N/A	ns
		XA6SLX75	5.09	N/A	5.87	N/A	ns
		XA6SLX75T	5.09	N/A	5.87	N/A	ns
		XA6SLX100	N/A	N/A	6.44	N/A	ns
		XQ6SLX75	N/A	N/A	5.87	7.95	ns
		XQ6SLX75T	5.09	N/A	5.87	N/A	ns
		XQ6SLX150	N/A	N/A	6.06	7.93	ns
		XQ6SLX150T	5.50	N/A	6.06	N/A	ns

Notes:

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
2. DCM output jitter is already included in the timing calculation.

Table 73: **Global Clock Setup and Hold With DCM in Source-Synchronous Mode**

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
Input Setup and Hold Time Relative to Global Clock Input Signal for LVCMOS25 Standard.(1)							
T_{PSDCM0}/ T_{PHDCM0}	No Delay Global Clock and IFF(2) with DCM in Source-Synchronous Mode	XC6SLX4	0.71/0.65	N/A	0.72/1.22	1.58/1.18	ns
		XC6SLX9	0.71/0.69	0.71/1.19	0.72/1.36	1.58/1.18	ns
		XC6SLX16	0.86/0.52	0.92/0.57	1.04/0.60	1.02/1.06	ns
		XC6SLX25	0.84/0.58	0.90/0.59	1.01/0.59	1.58/1.07	ns
		XC6SLX25T	0.84/0.58	0.90/0.59	1.01/0.59	N/A	ns
		XC6SLX45	0.85/0.70	0.90/0.76	0.98/0.79	1.34/1.34	ns
		XC6SLX45T	0.85/0.70	0.90/0.76	0.98/0.79	N/A	ns
		XC6SLX75	1.00/0.62	1.06/0.63	1.15/0.63	1.65/1.46	ns
		XC6SLX75T	1.00/0.71	1.06/0.72	1.15/0.72	N/A	ns
		XC6SLX100	0.81/0.68	0.81/0.69	0.94/0.69	1.42/2.07	ns
		XC6SLX100T	0.81/0.68	0.81/0.69	0.94/0.69	N/A	ns
		XC6SLX150	0.68/0.98	0.69/0.99	0.79/0.99	1.45/1.60	ns
		XC6SLX150T	0.68/0.98	0.69/0.99	0.79/0.99	N/A	ns
		XA6SLX4	0.81/0.74	N/A	0.72/1.36	N/A	ns
		XA6SLX9	0.81/0.74	N/A	0.72/1.36	N/A	ns
		XA6SLX16	1.01/0.56	N/A	1.04/0.60	N/A	ns
		XA6SLX25	0.94/0.76	N/A	1.06/0.77	N/A	ns
		XA6SLX25T	0.94/0.76	N/A	1.14/0.77	N/A	ns
		XA6SLX45	0.86/0.74	N/A	0.98/0.78	N/A	ns
		XA6SLX45T	0.86/0.74	N/A	0.98/0.78	N/A	ns
		XA6SLX75	1.02/0.71	N/A	1.15/0.72	N/A	ns
		XA6SLX75T	1.02/0.71	N/A	1.15/0.72	N/A	ns
		XA6SLX100	N/A	N/A	1.37/0.75	N/A	ns
		XQ6SLX75	N/A	N/A	1.15/0.72	1.65/1.46	ns
		XQ6SLX75T	1.02/0.71	N/A	1.15/0.72	N/A	ns
		XQ6SLX150	N/A	N/A	0.79/1.15	1.45/1.60	ns
		XQ6SLX150T	0.73/1.15	N/A	0.79/1.15	N/A	ns

Notes:

1. Setup and Hold times are measured over worst case conditions (process, voltage, temperature). Setup time is measured relative to the Global Clock input signal using the slowest process, highest temperature, and lowest voltage. Hold time is measured relative to the Global Clock input signal using the fastest process, lowest temperature, and highest voltage. These measurements include DCM CLK0 jitter.
2. IFF = Input Flip-Flop or Latch
3. Use IBIS to determine any duty-cycle distortion incurred using various standards.

Table 74: **Global Clock Setup and Hold With PLL in System-Synchronous Mode**

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
Input Setup and Hold Time Relative to Global Clock Input Signal for LVCMOS25 Standard.(1)							
T_{PSPLL}/ T_{PHPLL}	No Delay Global Clock and IFF(2) with PLL in System-Synchronous Mode	XC6SLX4	1.37/0.25	N/A	1.52/0.41	2.07/0.69	ns
		XC6SLX9	1.37/0.21	1.48/0.21	1.52/0.26	2.07/0.69	ns
		XC6SLX16	1.33/–0.03	1.53/–0.02	1.60/–0.02	1.57/0.48	ns
		XC6SLX25	1.65/0.28	1.71/0.28	1.91/0.28	2.44/0.76	ns
		XC6SLX25T	1.65/0.28	1.71/0.28	1.91/0.28	N/A	ns
		XC6SLX45	1.55/0.18	1.64/0.18	1.75/0.18	2.02/0.90	ns
		XC6SLX45T	1.55/0.18	1.64/0.18	1.75/0.18	N/A	ns
		XC6SLX75	1.77/0.21	1.89/0.21	2.13/0.21	2.46/0.53	ns
		XC6SLX75T	1.77/0.21	1.89/0.21	2.13/0.21	N/A	ns
		XC6SLX100	1.44/0.32	1.52/0.32	1.70/0.32	1.78/0.86	ns
		XC6SLX100T	1.44/0.32	1.52/0.32	1.70/0.32	N/A	ns
		XC6SLX150	1.39/0.49	1.48/0.49	1.67/0.49	1.94/0.94	ns
		XC6SLX150T	1.39/0.49	1.48/0.49	1.67/0.49	N/A	ns
		XA6SLX4	1.61/0.10	N/A	1.64/0.28	N/A	ns
		XA6SLX9	1.61/0.10	N/A	1.64/0.28	N/A	ns
		XA6SLX16	1.89/–0.08	N/A	1.72/–0.08	N/A	ns
		XA6SLX25	1.85/0.16	N/A	2.08/0.16	N/A	ns
		XA6SLX25T	1.85/0.16	N/A	2.17/0.16	N/A	ns
		XA6SLX45	1.58/0.07	N/A	1.87/0.03	N/A	ns
		XA6SLX45T	1.58/0.07	N/A	1.87/0.03	N/A	ns
		XA6SLX75	1.80/0.06	N/A	2.25/0.06	N/A	ns
		XA6SLX75T	1.80/0.06	N/A	2.25/0.06	N/A	ns
		XA6SLX100	N/A	N/A	2.34/0.14	N/A	ns
		XQ6SLX75	N/A	N/A	2.25/0.06	2.46/0.53	ns
		XQ6SLX75T	1.80/0.06	N/A	2.25/0.06	N/A	ns
		XQ6SLX150	N/A	N/A	1.79/0.37	1.94/0.94	ns
		XQ6SLX150T	1.43/0.37	N/A	1.79/0.37	N/A	ns

Notes:

1. Setup and Hold times are measured over worst case conditions (process, voltage, temperature). Setup time is measured relative to the Global Clock input signal using the slowest process, highest temperature, and lowest voltage. Hold time is measured relative to the Global Clock input signal using the fastest process, lowest temperature, and highest voltage. These measurements include PLL CLKOUT0 jitter.
2. IFF = Input Flip-Flop or Latch
3. Use IBIS to determine any duty-cycle distortion incurred using various standards.

Table 78: Duty Cycle Distortion and Clock-Tree Skew *(Cont'd)*

Symbol	Description	Device[1]	Speed Grade				Units
			-3	-3N	-2	-1L	
$T_{BUFIOSKEW}$	I/O clock tree skew across one clock region	LX4	0.06	N/A	0.06	0.07	ns
		LX9	0.06	0.06	0.06	0.07	ns
		LX16	0.06	0.06	0.06	0.07	ns
		LX25	0.06	0.06	0.06	0.07	ns
		LX25T	0.06	0.06	0.06	N/A	ns
		LX45	0.06	0.06	0.06	0.07	ns
		LX45T	0.06	0.06	0.06	N/A	ns
		LX75	0.06	0.06	0.06	0.07	ns
		LX75T	0.06	0.06	0.06	N/A	ns
		LX100	0.06	0.06	0.06	0.07	ns
		LX100T	0.06	0.06	0.06	N/A	ns
		LX150	0.06	0.06	0.06	0.07	ns
		LX150T	0.06	0.06	0.06	N/A	ns

Notes:

1. LXT devices are not available with a -1L speed grade. The LX4 is not available in -3N speed grade.
2. These parameters represent the worst-case duty cycle distortion observable at the pins of the device using LVDS output buffers. For cases where other I/O standards are used, IBIS can be used to calculate any additional duty cycle distortion that might be caused by asymmetrical rise/fall times.
3. The T_{CKSKEW} value represents the worst-case clock-tree skew observable between sequential I/O elements. Significantly less clock-tree skew exists for I/O registers that are close to each other and fed by the same or adjacent clock-tree branches. Use the Xilinx FPGA Editor and Timing Analyzer tools to evaluate clock skew specific to your application.
4. The T_{CKSKEW} is 0.43 ns for the XA6SLX100 device using a -2 speed grade and 0.22 ns for the XC6SLX100 devices using the -2 speed grade.

Table 79: Package Skew

Symbol	Description	Device	Package[2]	Value	Units
$T_{PKGSKEW}$	Package Skew[1]	LX4	TQG144	N/A	ps
			CPG196	23	ps
			CSG225	58	ps
		LX9	TQG144	N/A	ps
			CPG196	23	ps
			CSG225	58	ps
			FT(G)256	88	ps
			CSG324	64	ps
		LX16	CPG196	19	ps
			CSG225	70	ps
			FT(G)256	71	ps
			CSG324	54	ps
		LX25	FT(G)256	90	ps
			CSG324	61	ps
			FG(G)484	84	ps
		LX25T	CSG324	48	ps
			FG(G)484	112	ps

Table 79: **Package Skew *(Cont'd)***

Symbol	Description	Device	Package(2)	Value	Units
$T_{PKGSKEW}$	Package Skew(1)	LX45	CSG324	70	ps
			CS(G)484	99	ps
			FG(G)484	109	ps
			FG(G)676	138	ps
		LX45T	CSG324	75	ps
			CS(G)484	100	ps
			FG(G)484	95	ps
		LX75	CS(G)484	101	ps
			FG(G)484	107	ps
			FG(G)676	161	ps
		LX75T	CS(G)484	107	ps
			FG(G)484	110	ps
			FG(G)676	134	ps
		LX100	CS(G)484	95	ps
			FG(G)484	155	ps
			FG(G)676	144	ps
		LX100T	CS(G)484	88	ps
			FG(G)484	111	ps
			FG(G)676	147	ps
			FG(G)900	134	ps
		LX150	CS(G)484	84	ps
			FG(G)484	103	ps
			FG(G)676	115	ps
			FG(G)900	121	ps
		LX150T	CS(G)484	83	ps
			FG(G)484	88	ps
			FG(G)676	141	ps
			FG(G)900	120	ps

Notes:

1. These values represent the worst-case skew between any two SelectIO resources in the package: shortest delay to longest delay from Pad to Ball.
2. Some of the devices are available in both Pb and Pb-free (additional G) packages as standard ordering options. See DS160: *Spartan-6 Family Overview* for more information.

Table 80: **Sample Window**

Symbol	Description	Device(1)	Speed Grade				Units
			-3	-3N	-2	-1L	
T_{SAMP}	Sampling Error at Receiver Pins(2)	All	510	510	530	740	ps
T_{SAMP_BUFIO2}	Sampling Error at Receiver Pins using BUFIO2(3)	All	430	430	450	590	ps

Notes:

1. LXT devices are not available with a -1L speed grade.
2. This parameter indicates the total sampling error of Spartan-6 FPGA DDR input registers, measured across voltage, temperature, and process. The characterization methodology uses the DCM to capture the DDR input registers' edges of operation. These measurements include:
   - CLK0 DCM jitter
   - DCM accuracy (phase offset)
   - DCM phase shift resolution

   These measurements do not include package or clock tree skew.
3. This parameter indicates the total sampling error of Spartan-6 FPGA DDR input registers, measured across voltage, temperature, and process. The characterization methodology uses the BUFIO2 clock network and IODELAY2 to capture the DDR input registers' edges of operation. These measurements do not include package or clock tree skew.

Table 81: **Source-Synchronous Pin-to-Pin Setup/Hold and Clock-to-Out Using BUFIO2** ***(Cont’d)***

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
Pin-to-Pin Clock-to-Out Using BUFIO2							
$T_{ICKOFCS}$	OFF clock-to-out using BUFIO2 clock	XC6SLX4	5.51	N/A	6.95	8.45	ns
		XC6SLX9	5.51	5.89	6.95	8.45	ns
		XC6SLX16	5.31	5.70	6.67	8.21	ns
		XC6SLX25	5.53	6.00	7.02	8.72	ns
		XC6SLX25T	5.53	6.00	7.02	N/A	ns
		XC6SLX45	5.76	6.18	7.22	8.77	ns
		XC6SLX45T	5.76	6.18	7.22	N/A	ns
		XC6SLX75	5.94	6.46	7.57	9.72	ns
		XC6SLX75T	5.94	6.46	7.57	N/A	ns
		XC6SLX100	6.09	6.53	7.60	9.66	ns
		XC6SLX100T	6.09	6.53	7.60	N/A	ns
		XC6SLX150	6.29	6.69	7.81	9.94	ns
		XC6SLX150T	6.29	6.69	7.81	N/A	ns
		XA6SLX4	5.83	N/A	6.95	N/A	ns
		XA6SLX9	5.83	N/A	6.95	N/A	ns
		XA6SLX16	5.65	N/A	6.68	N/A	ns
		XA6SLX25	5.85	N/A	7.03	N/A	ns
		XA6SLX25T	5.85	N/A	7.03	N/A	ns
		XA6SLX45	6.07	N/A	7.25	N/A	ns
		XA6SLX45T	6.07	N/A	7.25	N/A	ns
		XA6SLX75	6.26	N/A	7.57	N/A	ns
		XA6SLX75T	6.26	N/A	7.57	N/A	ns
		XA6SLX100	N/A	N/A	7.48	N/A	ns
		XQ6SLX75	N/A	N/A	7.57	9.72	ns
		XQ6SLX75T	6.26	N/A	7.57	N/A	ns
		XQ6SLX150	N/A	N/A	7.81	9.94	ns
		XQ6SLX150T	6.62	N/A	7.81	N/A	ns

Date	Version	Description of Revisions
01/10/11	1.11	Production release of XC6SLX4 and XC6SLX9 in the specific speed grades listed in Table 26 and Table 27 using ISE v12.4 software with speed specification v1.15 for the -4, -3, -3N, and -2 speed grades. Added note 3 to Table 27. Also updated the -1L speed grade requirements to ISE v12.4 software with speed specification v1.06. Revised -3N definition throughout the document. Added note 4 to Table 2 and updated note 5. Added information on V_{CCINT} to note 1 in Table 5. Updated Networking Applications -3 values in Table 25 to match improvements made in ISE v12.4. In Table 28, added note 1 and revised the T_{IOTP} values for LVDS_33, LVDS_25, MINI_LVDS_33, MINI_LVDS_25, RSDS_33, RSDS_25, TMDS_33. PPDS_33, and PPDS_25. Added note 3 to Table 55.
02/11/11	1.12	As described in XCN11008: *Product Discontinuation Notice For Spartan-6 LXT -4 Devices*, the -4 speed specifications have been discontinued. As outlined in page 2 of the XCN, designers currently using -4 speed specifications should rerun timing analysis using the new -3 speed specifications before moving to a replacement device. Updated the networking applications section of Table 25. Updated -2 speed specifications throughout document and added note 3 to Table 27 advising designers to use the -2 speed specification update (v1.17) with the ISE 12.4 software patch. Added F_{CLKDIV} to Table 37 and Table 38. Updated note 2 in Table 39. Updated units for $T_{SMCKCSO}$ and T_{BPICCO} in Table 47. Updated -1L in Table 71. Removed Note 2: *Package delay information is available for these device/package combinations. This information can be used to deskew the package* from Table 79.
03/31/11	2.0	Production release of XC6SLX45 in the -1L speed grades listed in Table 26 and Table 27 using ISE v13.1 software with -1L speed specification v1.06. In Table 39, removed values in the -1L column and added note 3 as IODELAY2 only supports Tap0 for lower-power devices. Updated copyright page 1 and Notice of Disclaimer.
05/20/11	2.1	Production release of XC6SLX100 and XC6SLX150 in the specific speed grades listed in Table 26 and Table 27 using ISE v13.1 software with -1L speed specification v1.06. Updated Table 27 and Note 7 with changes per XCN11012: *Speed File Change for -3N Devices*. Revised Switching Characteristics section for speed specifications: v1.18 for -3, -3N, and -2; including improvements in Table 73 through Table 77 and Table 81. Removed *Memory Controller Block* from the performance heading in Table 2 and revised Note 2. In Table 4, added Note 1 to C_{IN} and updated the description of R_{IN_TERM}. Updated Note 1 in Table 5. Updated Note 1 of Table 7. In Table 25, added and removed -1L specifications, increased the standard performance DDR3 specifications, removed the extended performance DDR3 row and updated Note 3 and Note 4. Clarified the introductory information for Table 28 and Table 30. In Table 32: Revised V_{MEAS} value for LVCMOS12; revised V_{REF} for LVDS_25, LVDS_33, BLVDS_25,MINI_LVDS_25, MINI_LVDS_33, RSDS_25, and RSDS_33; revised R_{REF} for BLVDS_25 and TMDS_33; and added Note 4 and Note 5. Updated Note 2 and Note 3 in Table 39. In Table 47, revised the values and description of T_{POR} including adding Note 3. Also in Table 47, augmented the description and added specifications for F_{RBCCK} and removed XC6SLX4 from F_{MCCK} (maximum frequency, parallel mode (Master SelectMAP/BPI). Added BUFGMUX to Table 48 title. Added Table 50. In Table 52, revised specifications for $T_{EXTFDVAR}$ and $F_{INJITTER}$. In Table 54 removed the 5 MHz < CLKIN_FREQ_DLL parameter in the LOCK_DLL description. In both Table 56 and Table 57, removed the 5 MHz < F_{CLKIN} parameter in the LOCK_FX description. In Table 58, updated description for PSCLK_FREQ and PSCLK_PULSE. Revised title and symbol of Table 70, added new speed specifications for -1L, and added Note 2. Added Table 71.
07/11/11	2.2	Added the Automotive XA Spartan-6 and Defense-grade Spartan-6Q devices to all appropriate tables while sometimes removing the XC6S nomenclature. Added expanded temperature range (Q) to all appropriate tables. Updated T_{SOL} packages in Table 1. Added R_{OUT_TERM} to Table 4. Updated Note 2 on Table 13. Production release of the XC6SLX4, XC6SLX9, XC6SLX16, XC6SLX25, XC6SLX75, XQ6SLX75, and XQ6SLX150 in Table 26 and Table 27 using ISE v13.2 software with -1L speed specification v1.07. Production release of the XA6SLX16, XA6SLX25T, XA6SLX45, XA6SLX45T, XQ6SLX75, XQ6SLX75T, XQ6SLX150, and XQ6SLX150T in Table 26 and Table 27 using ISE v13.2 software with -2 and -3 speed specification v1.19. Added Table 29: IOB Switching Characteristics for the Automotive XA Spartan-6 and the Spartan-6Q Devices(1). Updated CS(G)484 from CSG484 throughout data sheet. Clarified Note 3 in Table 39.
08/08/11	2.3	Production release of the XA6SLX25, XA6SLX75, and XA6SLX75T in Table 26 and Table 27 using ISE v13.2 software with -2 and -3 speed specification v1.19.

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